

MC79XX/MC79XXA/LM79XX

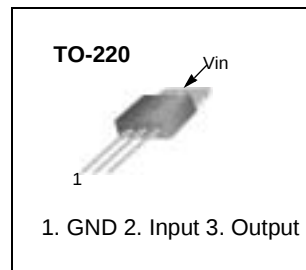
3-Terminal 1A Negative Voltage Regulator

Features

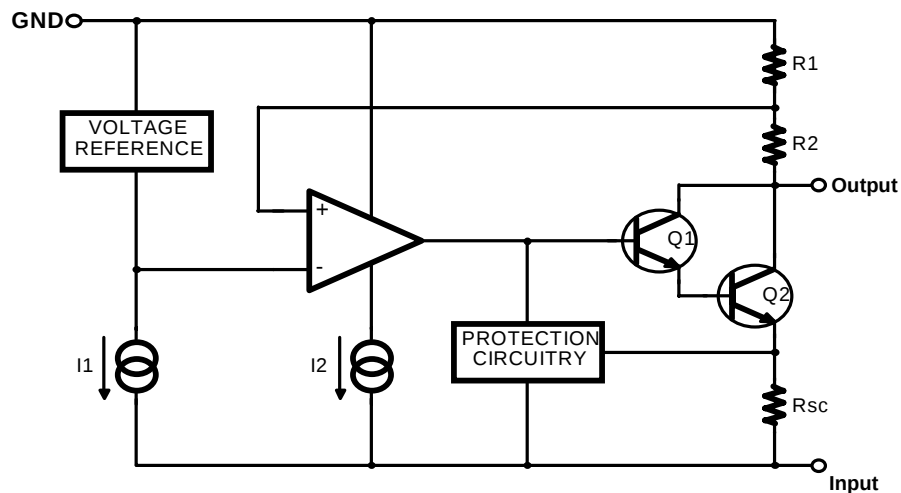
- Output Current in Excess of 1A
- Output Voltages of -5, -6, -8, -9, -10, -12, -15, -18 and -24V
- Internal Thermal Overload Protection
- Short Circuit Protection
- Output Transistor Safe Operating Area Compensation

Description

The MC79XX / MC79XXA / LM79XX series of three terminal negative regulators are available in TO-220 package and with several fixed output voltages, making them useful in a wide range of applications. Each type employs internal current limiting, thermal shut down and safe operating area protection, making it essentially indestructible.



Internal Block Diagram



Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Input Voltage	V_I	-35	V
Thermal Resistance Junction-Case (Note1)	$R_{\theta JC}$	5	°C/W
Thermal Resistance Junction-Air (Note1, 2)	$R_{\theta JA}$	65	
Operating Temperature Range	T_{OPR}	0 ~ +125	°C
Storage Temperature Range	T_{STG}	-65 ~ +150	°C

Note:

- Thermal resistance test board
Size: 76.2mm * 114.3mm * 1.6mm(1S0P)
JEDEC standard: JESD51-3, JESD51-7
- Assume no ambient airflow

Electrical Characteristics (MC7905/LM7905)

(V_I = -10V, I_O = 500mA, $0^\circ\text{C} \leq T_J \leq +125^\circ\text{C}$, C_I = 2.2 μ F, C_O = 1 μ F, unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Output Voltage	V_O	$T_J = +25^\circ\text{C}$	-4.8	-5.0	-5.2	V
		$I_O = 5\text{mA to } 1\text{A}$, $P_O \leq 15\text{W}$ $V_I = -7\text{V to } -20\text{V}$	-4.75	-5.0	-5.25	
Line Regulation (Note3)	ΔV_O	$T_J = +25^\circ\text{C}$				mV
		$V_I = -7\text{V to } -25\text{V}$	-	35	100	
		$V_I = -8\text{V to } -12\text{V}$	-	8	50	
Load Regulation (Note3)	ΔV_O	$T_J = +25^\circ\text{C}$ $I_O = 5\text{mA to } 1.5\text{A}$	-	10	100	mV
		$T_J = +25^\circ\text{C}$ $I_O = 250\text{mA to } 750\text{mA}$	-	3	50	
Quiescent Current	I_Q	$T_J = +25^\circ\text{C}$	-	3	6	mA
Quiescent Current Change	ΔI_Q	$I_O = 5\text{mA to } 1\text{A}$	-	0.05	0.5	mA
		$V_I = -8\text{V to } -25\text{V}$	-	0.1	0.8	
Temperature Coefficient of V_D	$\Delta V_O/\Delta T$	$I_O = 5\text{mA}$	-	- 0.4	-	mV/°C
Output Noise Voltage	V_N	$f = 10\text{Hz to } 100\text{kHz}$ $T_A = +25^\circ\text{C}$	-	40	-	μV
Ripple Rejection	RR	$f = 120\text{Hz}$ $\Delta V_I = 10\text{V}$	54	60	-	dB
Dropout Voltage	V_D	$T_J = +25^\circ\text{C}$ $I_O = 1\text{A}$	-	2	-	V
Short Circuit Current	I_{SC}	$T_J = +25^\circ\text{C}$, $V_I = -35\text{V}$	-	300	-	mA
Peak Current	I_{PK}	$T_J = +25^\circ\text{C}$	-	2.2	-	A

Note

- Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC7906) (Continued)(V_I = -11V, I_O = 500mA, 0°C ≤ T_J ≤ +125°C, C_I = 2.2μF, C_O = 1μF, unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
Output Voltage	VO	TJ = +25°C		-5.75	-6	-6.25	V
		IO = 5mA to 1A, PO ≤ 15W VI = -9V to -21V		-5.7	-6	-6.3	
Line Regulation (Note1)	ΔVO	TJ = +25°C	VI = -8V to -25V	-	10	120	mV
			VI = -9V to -13V	-	5	60	
Load Regulation (Note1)	ΔVO	TJ = +25°C IO = 5mA to 1.5A		-	10	120	mV
		TJ =+25°C IO = 250mA to 750mA		-	3	60	
Quiescent Current	IQ	TJ =+25°C		-	3	6	mA
Quiescent Current Change	ΔIQ	IO = 5mA to 1A		-	0.05	0.5	mA
		VI = -8V to -25V		-	0.1	1.3	
Temperature Coefficient of VD	ΔVo/ΔT	IO = 5mA		-	-0.5	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100kHz TA =+25°C		-	130	-	μV
Ripple Rejection	RR	f = 120Hz ΔVI = 10V		54	60	-	dB
Dropout Voltage	VD	TJ = +25°C IO = 1A		-	2	-	V
Short Circuit Current	ISC	TJ = +25°C, VI = -35V		-	300	-	mA
Peak Current	IPK	TJ = +25°C		-	2.2	-	A

Note

1. Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC7908) (Continued)(V_I = -14V, I_O = 500mA, 0°C ≤ T_J ≤ +125°C, C_I = 2.2μF, C_O = 1μF, unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Output Voltage	V _O	T _J = +25°C	-7.7	-8	-8.3	V
		I _O = 5mA to 1A, P _O ≤ 15W V _I = -10V to -23V	-7.6	-8	-8.4	
Line Regulation (Note1)	ΔV _O	T _J = +25°C				mV
		V _I = -10.5V to -25V V _I = -11V to -17V	- -	10 5	160 80	
Load Regulation (Note1)	ΔV _O	T _J = +25°C I _O = 5mA to 1.5A	-	12	160	mV
		T _J = +25°C I _O = 250mA to 750mA	-	4	80	
Quiescent Current	I _Q	T _J = +25°C	-	3	6	mA
Quiescent Current Change	ΔI _Q	I _O = 5mA to 1A	-	0.05	0.5	mA
		V _I = -10.5V to -25V	-	0.1	1	
Temperature Coefficient of V _D	ΔV _O /ΔT	I _O = 5mA	-	-0.6	-	mV/°C
Output Noise Voltage	V _N	f = 10Hz to 100kHz T _A = +25°C	-	175	-	μV
Ripple Rejection	RR	f = 120Hz ΔV _I = 10V	54	60	-	dB
Dropout Voltage	V _D	T _J = +25°C I _O = 1A	-	2	-	V
Short Circuit Current	I _{SC}	T _J = +25°C, V _I = -35V	-	300	-	mA
Peak Current	I _{PK}	T _J = +25°C	-	2.2	-	A

Note

1. Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC7909) (Continued)(V_I = -15V, I_O = 500mA, 0°C ≤ T_J ≤ +125°C, C_I = 2.2μF, C_O = 1μF, unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Output Voltage	V _O	T _J = +25°C	-8.7	-9.0	-9.3	V
		I _O = 5mA to 1A, P _O ≤ 15W V _I = -1.5V to -23V	-8.6	-9.0	-9.4	
Line Regulation (Note1)	ΔV _O	T _J = +25°C				mV
		V _I = -11.5V to -26V V _I = -12V to -18V	-	10 5	180 90	
Load Regulation (Note1)	ΔV _O	T _J = +25°C I _O = 5mA to 1.5A	-	12	180	mV
		T _J = +25°C I _O = 250mA to 750mA	-	4	90	
Quiescent Current	I _Q	T _J = +25°C	-	3	6	mA
Quiescent Current Change	ΔI _Q	I _O = 5mA to 1A	-	0.05	0.5	mA
		V _I = -11.5V to -26V	-	0.1	1	
Temperature Coefficient of V _D	ΔV _O /ΔT	I _O = 5mA	-	-0.6	-	mV/°C
Output Noise Voltage	V _N	f = 10Hz to 100kHz T _A = +25°C	-	175	-	μV
Ripple Rejection	RR	f = 120Hz ΔV _I = 10V	54	60	-	dB
Dropout Voltage	V _D	T _J = +25°C I _O = 1A	-	2	-	V
Short Circuit Current	I _{SC}	T _J = +25°C, V _I = -35V	-	300	-	mA
Peak Current	I _{PK}	T _J = +25°C	-	2.2	-	A

Note:

1. Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC7910) (Continued)(V_I = -17V, I_O = 500mA, 0°C ≤ T_J ≤ +125°C, C_I = 2.2μF, C_O = 1μF, unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Output Voltage	V _O	T _J = +25°C	-9.6	-10	-10.4	V
		I _O = 5mA to 1A, P _d ≤ 15W V _I = -12V to -28	-9.5	-10	-10.5	
Line Regulation (Note1)	ΔV _O	T _J = +25°C				mV
		V _I = -12.5V to -28V	-	12	200	
		V _I = -14V to -20V	-	6	100	
Load Regulation (Note1)	ΔV _O	T _J = +25°C I _O = 5mA to 1.5A	-	12	200	mV
		T _J = +25°C I _O = 250mA to 750mA	-	4	100	
Quiescent Current	I _Q	T _J = +25°C	-	3	6	mA
Quiescent Current Change	ΔI _Q	I _O = 5mA to 1A	-	0.05	0.5	mA
		V _I = -12.5V to -28V	-	0.1	1	
Temperature Coefficient of V _O	ΔV _O /ΔT	I _O = 5mA	-	-1	-	mV/°C
Output Noise Voltage	V _N	10Hz ≤ f ≤ 100kHz T _A = +25°C	-	280	-	μV
Ripple Rejection	RR	f = 120Hz ΔV _I = 10V	54	60	-	dB
Dropout Voltage	V _D	T _J = +25°C I _O = 1A	-	2	-	V
Short Circuit Current	I _{SC}	T _J = +25°C, V _I = -35V	-	300	-	mA
Peak Current	I _{PK}	T _J = +25°C	-	2.2	-	A

Note:

1. Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC7912) (Continued)(V_I = -19V, I_O = 500mA, 0°C ≤ T_J ≤ +125°C, C_I = 2.2μF, C_O = 1μF, unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Output Voltage	V _O	T _J = +25°C	-11.5	-12	-12.5	V
		I _O = 5mA to 1A, P _O ≤ 15W V _I = -15.5V to -27V	-11.4	-12	-12.6	
Line Regulation (Note1)	ΔV _O	T _J = +25°C				mV
		V _I = -14.5V to -30V	-	12	240	
		V _I = -16V to -22V	-	6	120	
Load Regulation (Note1)	ΔV _O	T _J = +25°C I _O = 5mA to 1.5A	-	12	240	mV
		T _J = +25°C I _O = 250mA to 750mA	-	4	120	
Quiescent Current	I _Q	T _J = +25°C	-	3	6	mA
Quiescent Current Change	ΔI _Q	I _O = 5mA to 1A	-	0.05	0.5	mA
		V _I = -14.5V to -30V	-	0.1	1	
Temperature Coefficient of V _D	ΔV _O /ΔT	I _O = 5mA	-	-0.8	-	mV/°C
Output Noise Voltage	V _N	f = 10Hz to 100kHz T _A = +25°C	-	200	-	μV
Ripple Rejection	RR	f = 120Hz ΔV _I = 10V	54	60	-	dB
Dropout Voltage	V _D	T _J = +25°C I _O = 1A	-	2	-	V
Short Circuit Current	I _{SC}	T _J = +25°C, V _I = -35V	-	300	-	mA
Peak Current	I _{PK}	T _J = +25°C	-	2.2	-	A

Note:

1. Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC7915) (Continued)(V_I = -23V, I_O = 500mA, 0°C ≤ T_J ≤ +125°C, C_I = 2.2μF, C_O = 1μF, unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Output Voltage	V _O	T _J = +25°C	-14.4	-15	-15.6	V
		I _O = 5mA to 1A, P _O ≤ 15W V _I = -18V to -30V	-14.25	-15	-15.75	
Line Regulation (Note1)	ΔV _O	T _J = +25°C				mV
		V _I = -17.5V to -30V	-	12	300	
		V _I = -20V to -26V	-	6	150	
Load Regulation (Note1)	ΔV _O	T _J = +25°C I _O = 5mA to 1.5A	-	12	300	mV
		T _J = +25°C I _O = 250mA to 750mA	-	4	150	
Quiescent Current	I _Q	T _J = +25°C	-	3	6	mA
Quiescent Current Change	ΔI _Q	I _O = 5mA to 1A	-	0.05	0.5	mA
		V _I = -17.5V to -30V	-	0.1	1	
Temperature Coefficient of V _D	ΔV _O /ΔT	I _O = 5mA	-	-0.9	-	mV/°C
Output Noise Voltage	V _N	f = 10Hz to 100kHz T _A = +25°C	-	250	-	μV
Ripple Rejection	RR	f = 120Hz ΔV _I = 10V	54	60	-	dB
Dropout Voltage	V _D	T _J = +25°C I _O = 1A	-	2	-	V
Short Circuit Current	I _{SC}	T _J = +25°C, V _I = -35V	-	300	-	mA
Peak Current	I _{PK}	T _J = +25°C	-	2.2	-	A

Note:

1. Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC7918) (Continued)(V_I = -27V, I_O = 500mA, 0°C ≤ T_J ≤ +125°C, C_I = 2.2μF, C_O = 1μF, unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Output Voltage	V _O	T _J = +25°C	-17.3	-18	-18.7	V
		I _O = 5mA to 1A, P _O ≤ 15W V _I = -22.5V to -33V	-17.1	-18	-18.9	
Line Regulation (Note1)	ΔV _O	T _J = +25°C				mV
		V _I = -21V to -33V	-	15	360	
		V _I = -24V to -30V	-	8	180	
Load Regulation (Note1)	ΔV _O	T _J = +25°C I _O = 5mA to 1.5A	-	15	360	mV
		T _J = +25°C I _O = 250mA to 750mA	-	5	180	
Quiescent Current	I _Q	T _J = +25°C	-	3	6	mA
Quiescent Current Change	ΔI _Q	I _O = 5mA to 1A	-	0.05	0.5	mA
		V _I = -21V to -33V	-	0.1	1	
Temperature Coefficient of V _D	ΔV _O /ΔT	I _O = 5mA	-	-1	-	mV/°C
Output Noise Voltage	V _N	f = 10Hz to 100kHz T _A = +25°C	-	300	-	μV
Ripple Rejection	RR	f = 120Hz ΔV _I = 10V	54	60	-	dB
Dropout Voltage	V _D	T _J = +25°C I _O = 1A	-	2	-	V
Short Circuit Current	I _{SC}	T _J = +25°C, V _I = -35V	-	300	-	mA
Peak Current	I _{PK}	T _J = +25°C	-	2.2	-	A

Note:

1. Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC7924) (Continued)(V_I = -33V, I_O = 500mA, 0°C ≤ T_J ≤ +125°C, C_I = 2.2μF, C_O = 1μF, unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Output Voltage	V _O	T _J = +25°C	-23	-24	-25	V
		I _O = 5mA to 1A, P _O ≤ 15W V _I = -27V to -38V	-22.8	-24	-25.2	
Line Regulation (Note1)	ΔV _O	T _J = +25°C				mV
		V _I = -27V to -38V	-	15	480	
		V _I = -30V to -36V	-	8	180	
Load Regulation (Note1)	ΔV _O	T _J = +25°C I _O = 5mA to 1.5A	-	15	480	mV
		T _J = +25°C I _O = 250mA to 750mA	-	5	240	
Quiescent Current	I _Q	T _J = +25°C	-	3	6	mA
Quiescent Current Change	ΔI _Q	I _O = 5mA to 1A	-	0.05	0.5	mA
		V _I = -27V to -38V	-	0.1	1	
Temperature Coefficient of V _D	ΔV _O /ΔT	I _O = 5mA	-	-1	-	mV/°C
Output Noise Voltage	V _N	f = 10Hz to 100kHz T _A = +25°C	-	400	-	μV
Ripple Rejection	RR	f = 120Hz ΔV _I = 10V	54	60	-	dB
Dropout Voltage	V _D	T _J = +25°C I _O = 1A	-	2	-	V
Short Circuit Current	I _{SC}	T _J = +25°C, V _I = -35V	-	300	-	mA
Peak Current	I _{PK}	T _J = +25°C	-	2.2	-	A

Note:

1. Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC7905A) (Continued)(V_I = -10V, I_O = 500mA, 0°C ≤ T_J ≤ +125°C, C_I = 2.2μF, C_O = 1μF, unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Output Voltage	V _O	T _J = +25°C	-4.9	-5.0	-5.1	V
		I _O = 5mA to 1A, P _O ≤ 15W V _I = -7V to -20V	- 4.8	-5.0	-5.2	
Line Regulation (Note1)	ΔV _O	T _J = +25°C	-	5	50	mV
		V _I = -7V to -20V I _O =1A		2	25	
		V _I = -8V to -12V I _O =1A	-	7	50	
		V _I = -7.5V to -25V	-	7	50	
Load Regulation (Note1)	ΔV _O	T _J = +25°C, I _O = 5mA to 1.5A	-	10	100	mV
		T _J = +25°C I _O = 250mA to 750mA	-	3	50	
Quiescent Current	I _Q	T _J = +25°C	-	3	6	mA
Quiescent Current Change	ΔI _Q	I _O = 5mA to 1A	-	0.05	0.5	mA
		V _I = -8V to -25V	-	0.1	0.8	
Temperature Coefficient of V _D	ΔV _O /ΔT	I _O = 5mA	-	- 0.4	-	mV/°C
Output Noise Voltage	V _N	f = 10Hz to 100kHz T _A = +25°C	-	40	-	μV
Ripple Rejection	RR	f = 120Hz ΔV _I = 10V	54	60	-	dB
Dropout Voltage	V _D	T _J = +25°C I _O = 1A	-	2	-	V
Short Circuit Current	I _{SC}	T _J = +25°C, V _I = -35V	-	300	-	mA
Peak Current	I _{PK}	T _J = +25°C	-	2.2	-	A

Note:

1. Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC7912A) (Continued)(V_I = -19V, I_O = 500mA, 0°C ≤ T_J ≤ +125°C, C_I = 2.2μF, C_O = 1μF, unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
Output Voltage	V _O	T _J = +25°C		-11.75	-12	-12.25	V
		I _O = 5mA to 1A, P _O ≤ 15W V _I = -15.5V to -27V		-11.5	-12	-12.5	
Line Regulation (Note1)	ΔV _O	T _J = +25°C	V _I = -14.5V to -27V I _O = 1A	-	12	120	mV
			V _I = -16V to -22V I _O = 1A	-	6	60	
		V _I = -14.8V to -30V		-	12	120	
		V _I = -16V to -22V, I _O = 1A		-	12	120	
Load Regulation (Note1)	ΔV _O	T _J = +25°C I _O = 5mA to 1.5A		-	12	150	mV
		T _J = +25°C I _O = 250mA to 750mA		-	4	75	
Quiescent Current	I _Q	T _J = +25°C		-	3	6	mA
Quiescent Current Change	ΔI _Q	I _O = 5mA to 1A		-	0.05	0.5	mA
		V _I = -15V to -30V		-	0.1	1	
Temperature Coefficient of V _D	ΔV _O /ΔT	I _O = 5mA		-	-0.8	-	mV/°C
Output Noise Voltage	V _N	f = 10Hz to 100kHz T _A = +25°C		-	200	-	μV
Ripple Rejection	RR	f = 120Hz ΔV _I = 10V		54	60	-	dB
Dropout Voltage	V _D	T _J = +25°C I _O = 1A		-	2	-	V
Short Circuit Current	I _{SC}	T _J = +25°C, V _I = -35V		-	300	-	mA
Peak Current	I _{PK}	T _J = +25°C		-	2.2	-	A

Note:

1. Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC7915A) (Continued)(V_I = -23V, I_O = 500mA, 0°C ≤ T_J ≤ +125°C, C_I = 2.2μF, C_O = 1μF, unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
Output Voltage	V _O	T _J = +25°C		-14.7	-15	-15.3	V
		I _O = 5mA to 1A, P _O ≤ 15W V _I = -18V to -30V		-14.4	-15	-15.6	
Line Regulation (Note1)	ΔV _O	T _J = +25°C	V _I = -17.5V to -30V I _O = 1A	-	12	150	mV
			V _I = -20V to -26V I _O = 1A	-	6	75	
		V _I = -17.9V to -30V		-	12	150	
		V _I = -20V to -26V, I _O = 1A		-	6	150	
Load Regulation (Note1)	ΔV _O	T _J = +25°C I _O = 5mA to 1.5A		-	12	150	mV
		T _J = +25°C I _O = 250mA to 750mA		-	4	75	
Quiescent Current	I _Q	T _J = +25°C		-	3	6	mA
Quiescent Current Change	ΔI _Q	I _O = 5mA to 1A		-	0.05	0.5	mA
		V _I = -18.5V to -30V		-	0.1	1	
Temperature Coefficient of V _D	ΔV _O /ΔT	I _O = 5mA		-	-0.9	-	mV/°C
Output Noise Voltage	V _N	f = 10Hz to 100kHz T _A = +25°C		-	250	-	μV
Ripple Rejection	RR	f = 120Hz ΔV _I = 10V		54	60	-	dB
Dropout Voltage	V _D	T _J = +25°C I _O = 1A		-	2	-	V
Short Circuit Current	I _{SC}	T _J = +25°C, V _I = -35V		-	300	-	mA
Peak Current	I _{PK}	T _J = +25°C		-	2.2	-	A

Note:

1. Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Typical Performance Characteristics

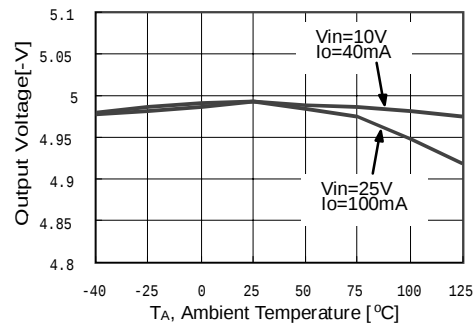


Figure 1. Output Voltage

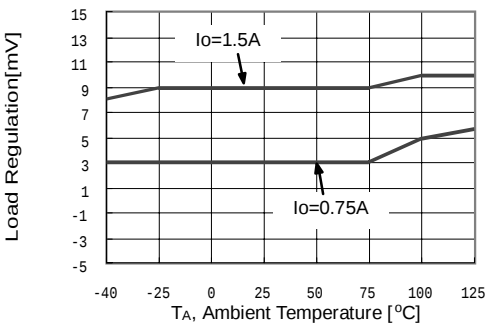


Figure 2. Load Regulation

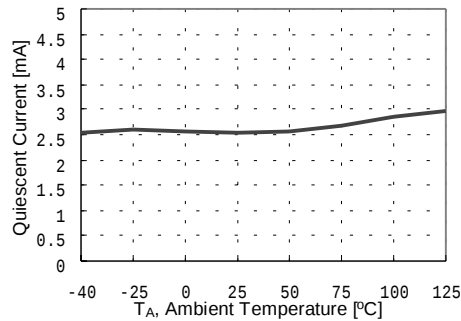


Figure 3. Quiescent Current

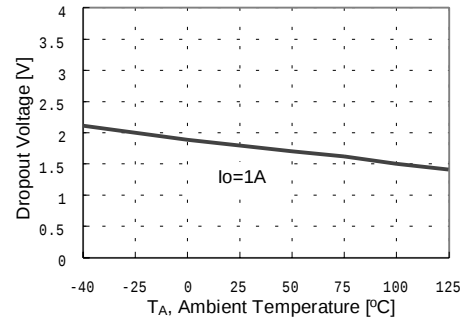


Figure 4. Dropout Voltage

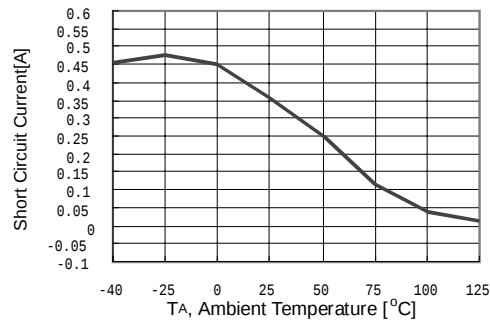


Figure 5. Short Circuit Current

Typical Applications

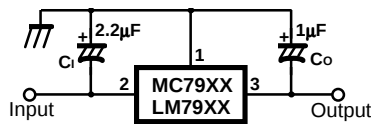


Figure 6. Negative Fixed output regulator

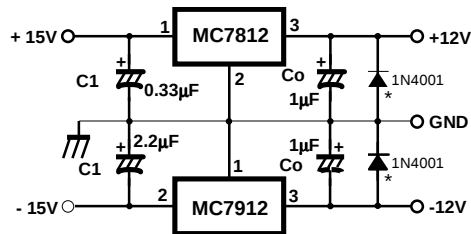


Figure 7. Split power supply ($\pm 12V/1A$)

Notes:

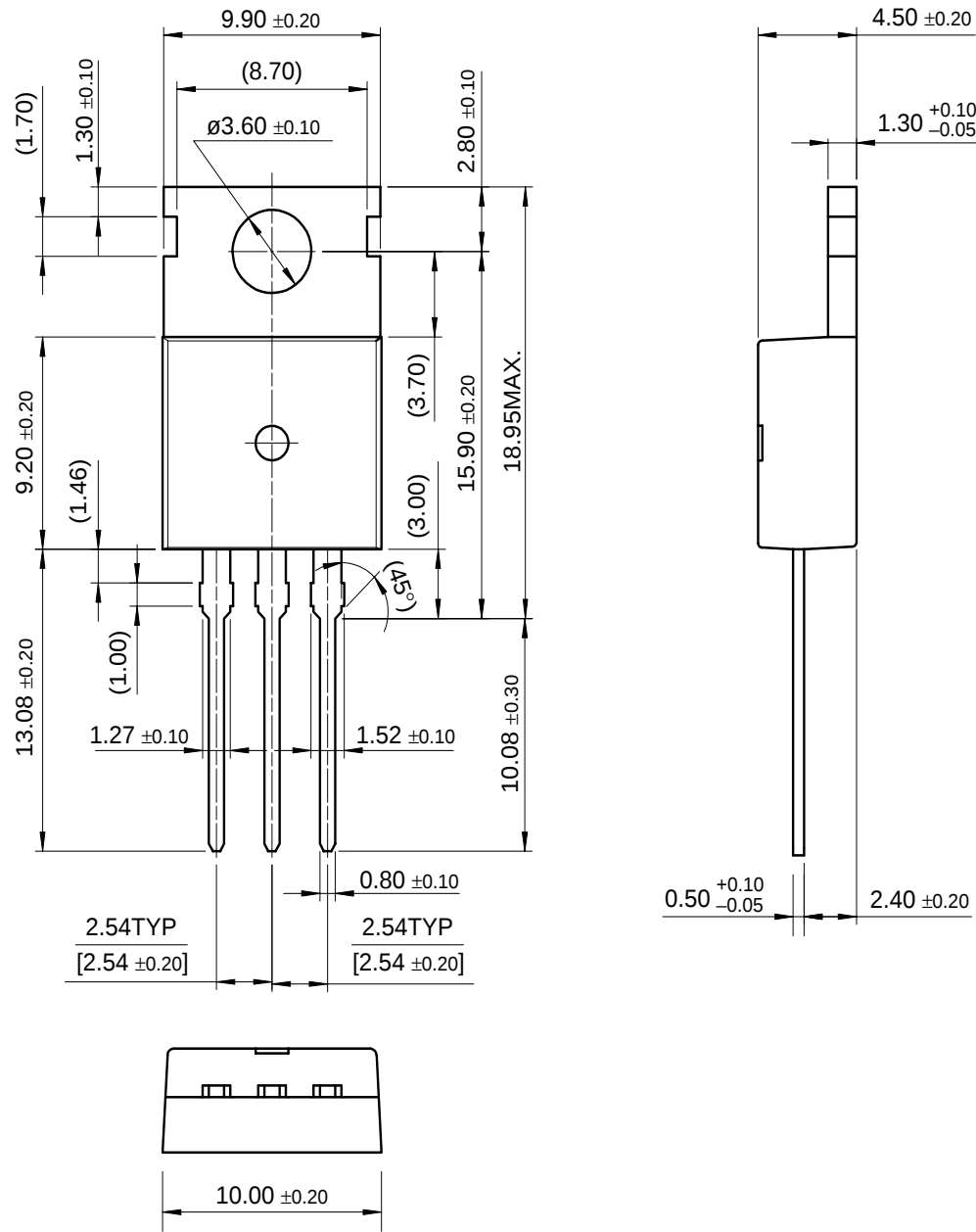
- (1) To specify an output voltage, substitute voltage value for "XX "
- (2) Required for stability. For value given, capacitor must be solid tantalum. If aluminium electrolytics are used, at least ten times value shown should be selected. C₁ is required if regulator is located an appreciable distance from power supply filter.
- (3) To improve transient response. If large capacitors are used, a high current diode from input to output (1N4001 or similar) should be introduced to protect the device from momentary input short circuit.

Mechanical Dimensions

Package

Dimensions in millimeters

TO-220



Ordering Information

Product Number	Output Voltage Tolerance	Package	Operating Temperature
LM7905CT	±4%	TO-220	0 ~ +125°C
Product Number	Output Voltage Tolerance	Package	Operating Temperature
MC7905CT	±4%	TO-220	0 ~ +125°C
MC7906CT			
MC7908CT			
MC7909CT			
MC7910CT			
MC7912CT			
MC7915CT			
MC7918CT			
MC7924CT			
MC7905ACT	±2%		
MC7912ACT			
MC7915ACT			

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.